# General Purpose Transistors

### **PNP Silicon**

### Features

- S and NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q101 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

#### MAXIMUM RATINGS (T<sub>A</sub> = 25°C unless otherwise noted)

Rating	Symbol	Value	Unit
Collector-Emitter Voltage BC856, SBC856 BC857, SBC857 BC858, NSVBC858, BC859	V <sub>CEO</sub>	-65 -45 -30	V
Collector-Base Voltage BC856, SBC856 BC857, SBC857 BC858, NSVBC858, BC859	V <sub>CBO</sub>	80 50 30	V
Emitter-Base Voltage	V <sub>EBO</sub>	-5.0	V
Collector Current – Continuous	Ι <sub>C</sub>	-100	mAdc
Collector Current – Peak	Ι <sub>C</sub>	-200	mAdc

#### THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation FR-5 Board, (Note 1) T <sub>A</sub> = 25°C Derate above 25°C	P <sub>D</sub>	225 1.8	mW mW/°C
Thermal Resistance, Junction-to-Ambient	$R_{\theta J A}$	556	°C/W
Total Device Dissipation Alumina Substrate, (Note 2) T <sub>A</sub> = 25°C Derate above 25°C	P <sub>D</sub>	300 2.4	mW mW/°C
Thermal Resistance, Junction-to-Ambient	$R_{\thetaJA}$	417	°C/W
Junction and Storage Temperature	T <sub>J</sub> , T <sub>stg</sub>	-55 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

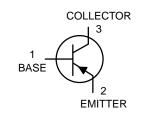
1.  $FR-5 = 1.0 \times 0.75 \times 0.062$  in.

2. Alumina = 0.4 x 0.3 x 0.024 in 99.5% alumina.



### **ON Semiconductor®**

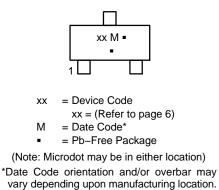
www.onsemi.com





SOT-23 (TO-236) CASE 318 STYLE 6

### MARKING DIAGRAM



### **ORDERING INFORMATION**

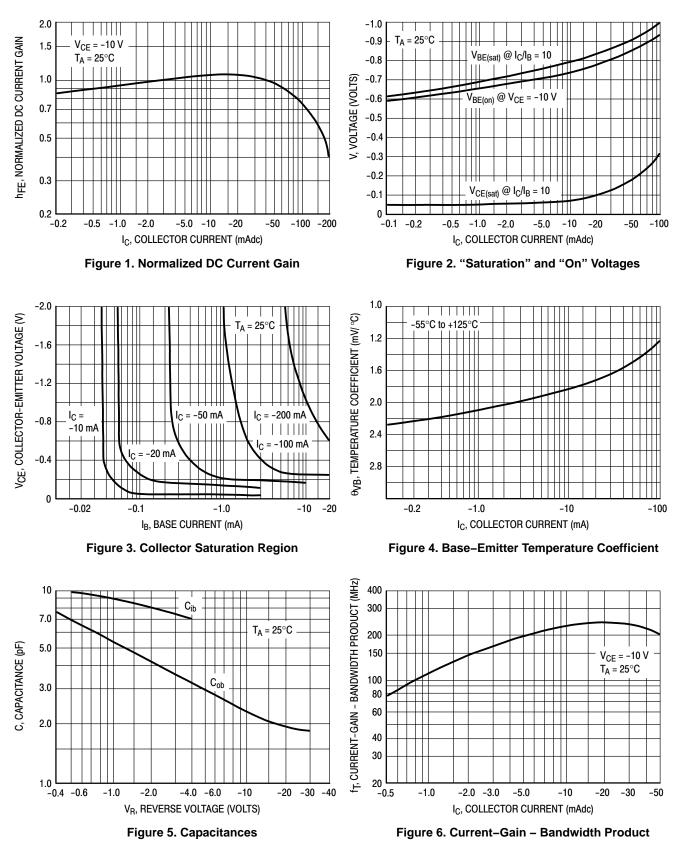
See detailed ordering and shipping information in the package dimensions section on page 6 of this data sheet.

## **ELECTRICAL CHARACTERISTICS** ( $T_A = 25^{\circ}C$ unless otherwise noted)

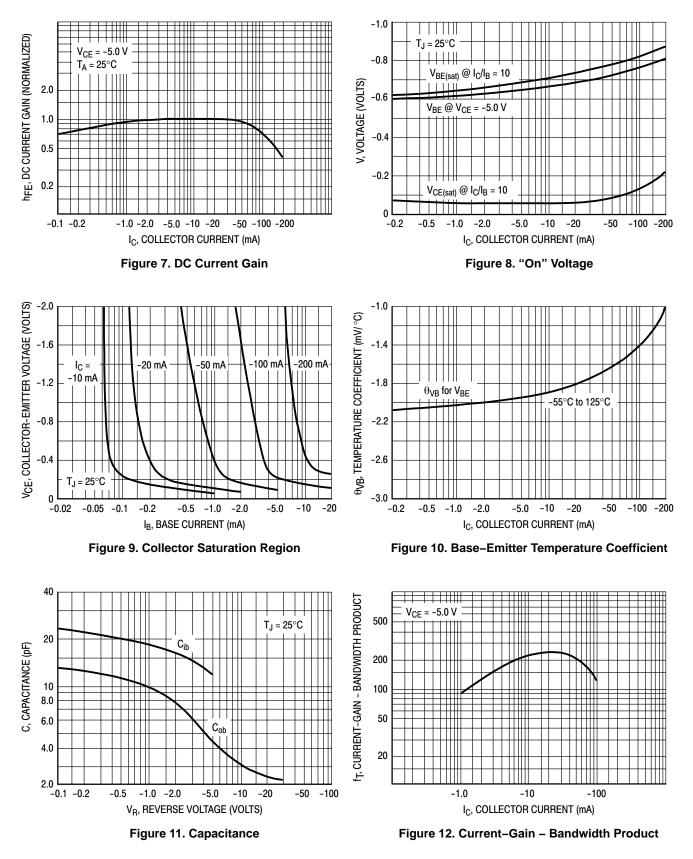
Characteristic	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS					
Collector – Emitter Breakdown VoltageBC856, SBC856 Series(I <sub>C</sub> = -10 mA)BC857, SBC857 SeriesBC858, NSBVC858 BC859 Series	V <sub>(BR)CEO</sub>	-65 -45 -30	- - -	- - -	V
	V <sub>(BR)CES</sub>	80 50 30	- - -	- - -	V
	V <sub>(BR)CBO</sub>	80 50 30	- - -	- - -	V
$ \begin{array}{ll} \mbox{Emitter}-\mbox{Base Breakdown Voltage} & \mbox{BC856, SBC856 Series} \\ (I_E = -1.0 \ \mu A) & \mbox{BC857, SBC857 Series} \\ \mbox{BC858, NSVBC858, BC859 Series} \end{array} $	V <sub>(BR)EBO</sub>	-5.0 -5.0 -5.0	- - -	- - -	V
Collector Cutoff Current (V <sub>CB</sub> = $-30$ V) (V <sub>CB</sub> = $-30$ V, T <sub>A</sub> = $150^{\circ}$ C)	I <sub>CBO</sub>	_ _	_ _	-15 -4.0	nA μA
DN CHARACTERISTICS					
DC Current Gain BC856A, SBC856A, BC857A, SBC857A, BC858A $(I_C = -10 \ \mu A, V_{CE} = -5.0 \ V)$ BC856B, SBC856B, BC857B, BC857B, BC858B, NSVBC858B	h <sub>FE</sub>		90 150		-
BC857C, SBC857C BC858C		-	270	-	
$      (I_C = -2.0 \text{ mA}, \text{ V}_{CE} = -5.0 \text{ V}) \\            BC856A, \text{ SBC856A}, \text{ BC857A}, \\            SBC857A, \text{ BC858A} \\            BC856B, \text{ SBC856B}, \text{ BC857B}, \text{ SBC857B}, \text{ BC858B}, \\            BC856B, \text{ SBC856B}, \text{ BC857B}, \text{ SBC857B}, \text{ BC858B}, \\            BC856B, \text{ SBC856B}, \text{ BC857B}, \text{ SBC857B}, \text{ BC858B}, \\            BC856B, \text{ SBC856B}, \text{ SBC857B}, \text{ SBC857B}, \text{ BC858B}, \\            BC856B, \text{ SBC856B}, \text{ SBC857B}, \text{ SBC857B}, \text{ BC858B}, \\            BC856B, \text{ SBC856B}, \text{ SBC857B}, \text{ SBC857B}, \text{ SBC857B}, \text{ SBC857B}, \\            BC856B, \text{ SBC856B}, \text{ SBC856B}, \text{ SBC857B}, \text{ SBC857B}, \text{ SBC857B}, \text{ SBC857B}, \\            BC856B, \text{ SBC856B}, \text{ SBC856B}, \text{ SBC857B}, \text{ SBC857B}, \text{ SBC857B}, \text{ SBC857B}, \\            BC856B, \text{ SBC856B}, \text{ SBC856B}, \text{ SBC857B},  S$		125 220	180 290	250 475	
NSVBC858B, BC859B BC857C, SBC857C, BC858C, BC859C		420	520	800	
Collector – Emitter Saturation Voltage $(I_C = -10 \text{ mA}, I_B = -0.5 \text{ mA})$ $(I_C = -100 \text{ mA}, I_B = -5.0 \text{ mA})$	V <sub>CE(sat)</sub>			-0.3 -0.65	V
Base – Emitter Saturation Voltage ( $I_C = -10 \text{ mA}, I_B = -0.5 \text{ mA}$ ) ( $I_C = -100 \text{ mA}, I_B = -5.0 \text{ mA}$ )	V <sub>BE(sat)</sub>		-0.7 -0.9		V
Base – Emitter On Voltage ( $I_C = -2.0 \text{ mA}$ , $V_{CE} = -5.0 \text{ V}$ ) ( $I_C = -10 \text{ mA}$ , $V_{CE} = -5.0 \text{ V}$ )	V <sub>BE(on)</sub>	-0.6 -		-0.75 -0.82	V
SMALL-SIGNAL CHARACTERISTICS					
Current-Gain – Bandwidth Product ( $I_C = -10$ mA, $V_{CE} = -5.0$ Vdc, f = 100 MHz)	f <sub>T</sub>	100	_	_	MHz
Output Capacitance ( $V_{CB} = -10 \text{ V}, \text{ f} = 1.0 \text{ MHz}$ )	C <sub>ob</sub>	-	-	4.5	pF
Noise Figure (I <sub>C</sub> = -0.2 mA, V <sub>CE</sub> = -5.0 Vdc, R <sub>S</sub> = 2.0 kΩ, f = 1.0 kHz, BW = 200 Hz) BC856, SBC856, BC857, SBC857, BC858, NSVBC858 Series BC859 Series	NF			10 4.0	dB

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

#### BC857/BC858/BC859/SBC857/NSVBC858



#### BC856/SBC856



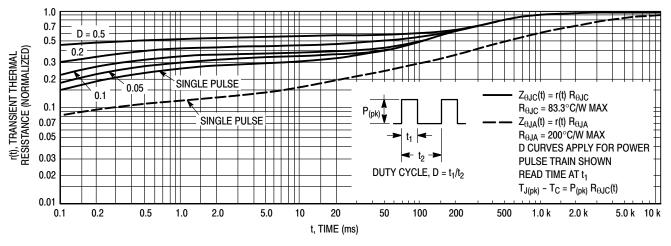


Figure 13. Thermal Response

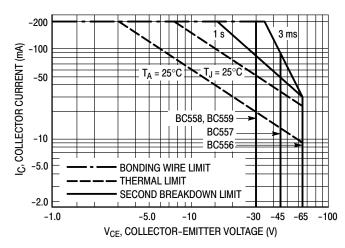


Figure 14. Active Region Safe Operating Area

The safe operating area curves indicate  $I_C-V_{CE}$  limits of the transistor that must be observed for reliable operation. Collector load lines for specific circuits must fall below the limits indicated by the applicable curve.

The data of Figure 14 is based upon  $T_{J(pk)} = 150^{\circ}C$ ;  $T_C$  or  $T_A$  is variable depending upon conditions. Pulse curves are valid for duty cycles to 10% provided  $T_{J(pk)} \le 150^{\circ}C$ .  $T_{J(pk)}$  may be calculated from the data in Figure 13. At high case or ambient temperatures, thermal limitations will reduce the power that can be handled to values less than the limitations imposed by the secondary breakdown.

#### **ORDERING INFORMATION**

Device	Marking	Package	Shipping $^{\dagger}$		
BC856ALT1G	3A	SOT-23	3,000 / Tape & Reel		
SBC856ALT1G*		(Pb-Free)			
BC856ALT3G			10,000 / Tape & Reel		
BC856BLT1G	3B	SOT-23	3,000 / Tape & Reel		
SBC856BLT1G*		(Pb-Free)			
BC856BLT3G			10,000 / Tape & Reel		
SBC856BLT3G*					
BC857ALT1G	3E	SOT-23	3,000 / Tape & Reel		
SBC857ALT1G*		(Pb-Free)			
BC857BLT1G	3F	SOT-23	3,000 / Tape & Reel		
SBC857BLT1G*		(Pb-Free)			
BC857BLT3G			10,000 / Tape & Reel		
NSVBC857BLT3G*					
BC857CLT1G	3G SOT-23 (Pb-Free)		3,000 / Tape & Reel		
SBC857CLT1G*		(Pb-Free)			
BC857CLT3G			10,000 / Tape & Reel		
BC858ALT1G	3J	SOT-23 (Pb-Free)	3,000 / Tape & Reel		
BC858BLT1G	ЗК	SOT-23			
NSVBC858BLT1G*		(Pb-Free)			
BC858BLT3G	3L	SOT-23 (Pb-Free)	10,000 / Tape & Reel		
BC858CLT1G		SOT-23 (Pb-Free)	3,000 / Tape & Reel		
BC858CLT3G		SOT-23 (Pb-Free)	10,000 / Tape & Reel		
BC859BLT1G	4B	SOT-23 (Pb-Free)	3,000 / Tape & Reel		
BC859BLT3G		SOT-23 (Pb-Free)	10,000 / Tape & Reel		
BC859CLT1G	4C	SOT-23 (Pb-Free)	3,000 / Tape & Reel		
BC859CLT3G		SOT-23 (Pb-Free)	10,000 / Tape & Reel		

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.
\*S and NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q101 Qualified and PPAP Capable.





© Semiconductor Components Industries, LLC, 2019

onsemi, ONSEMI, and other names, marks, and brands are registered and/or common law trademarks of Semiconductor Components Industries, LLC dba "onsemi" or its affiliates and/or subsidiaries in the United States and/or other countries. onsemi owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of onsemi's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. onsemi reserves the right to make changes at any time to any products or information herein, without notice. The information herein is provided "as-is" and onsemi makes no warranty, representation or guarantee regarding the accuracy of the information, product features, availability, functionality, or suitability of its products for any particular purpose, nor does **onsemi** assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using **onsemi** products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by **onsemi**. "Typical" parameters which may be provided in **onsemi** data sheets and/or specifications can and do vary in different applications and calcular performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. **onsemi** does not convey any license under any of its intellectual property rights nor the rights of others. **onsemi** products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use **onsemi** products for any such unintended or unauthorized application, Buyer shall indemnify and hold **onsemi** and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that **onsemi** was negligent regarding the design or manufacture of the part. **onsemi** is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

#### PUBLICATION ORDERING INFORMATION

#### LITERATURE FULFILLMENT:

#### TECHNICAL SUPPORT

onsemi Website: www.onsemi.com

Email Requests to: orderlit@onsemi.com

North American Technical Support: Voice Mail: 1 800-282-9855 Toll Free USA/Canada Phone: 011 421 33 790 2910

Europe, Middle East and Africa Technical Support: Phone: 00421 33 790 2910 For additional information, please contact your local Sales Representative

# **Mouser Electronics**

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

onsemi:

BC856ALT1BC856ALT1GBC856ALT3BC856ALT3GBC856BLT1BC856BLT1GBC856BLT3BC856BLT3BC857ALT1BC857ALT1GBC857BLT1BC857BLT1GBC857BLT3BC857BLT3GBC857CLT1BC857CLT1BC858ALT1BC858ALT1GBC858BLT1BC858BLT1GBC858BLT3GBC858CLT1BC858CLT1GBC858CLT3BC858CLT3GBC859BLT1BC859BLT1GBC859BLT3BC859BLT3GBC859CLT1BC859CLT3BC859CLT3GBC859BLT1BC859BLT1GBC859BLT3BC859BLT3GBC859CLT1BC859CLT3BC859CLT3GSBC857BLT1GSBC856ALT1GNSVBC858BLT1GSBC857CLT1GSBC856BLT1GSBC856BLT3GSBC857ALT1GBC857CLT3GNSVBC858CLT1GNSVBC857BLT3G